

LT5516

HNOLOGY 800MHz to 1.5GHz Direct Conversion Quadrature Demodulator

FEATURES

- Frequency Range: 800MHz to 1.5GHz
- High IIP3: 21.5dBm at 900MHz
- High IIP2: 52dBm
- Noise Figure: 12.8dB at 900MHz
- Conversion Gain: 4.3dB at 900MHz
- I/Q Gain Mismatch: 0.2dB
- Shutdown Mode
- 16-Lead QFN 4mm × 4mm Package with Exposed Pad

APPLICATIONS

- Cellular/PCS/UMTS Infrastructure
- High Linearity Direct Conversion I/Q Receiver
- High Linearity I/Q Demodulator

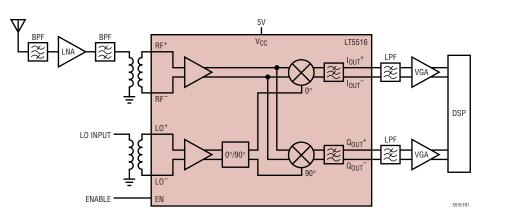
TYPICAL APPLICATION

DESCRIPTION

The LT[®]5516 is an 800MHz to 1.5GHz direct conversion quadrature demodulator optimized for high linearity receiver applications. It is suitable for communications receivers where an RF or IF signal is directly converted into I and Q baseband signals with bandwidth up to 260MHz. The LT5516 incorporates balanced I and Q mixers, LO buffer amplifiers and a precision, high frequency quadrature generator.

In an RF receiver, the high linearity of the LT5516 provides excellent spur-free dynamic range, even with fixed gain front end amplification. This direct conversion receiver can eliminate the need for intermediate frequency (IF) signal processing, as well as the corresponding requirements for image filtering and IF filtering. Channel filtering can be performed directly at the outputs of the I and Q channels. These outputs can interface directly to channelselect filters (LPFs) or to a baseband amplifier.

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I/Q Output Power, IM3 vs RF Input Power

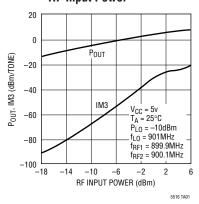


Figure 1. High Signal-Level I/Q Demodulator for Wireless Infrastructure

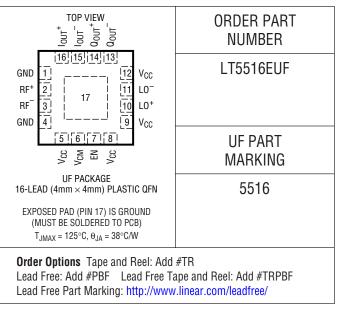


ABSOLUTE MAXIMUM RATINGS

(Note 1)

Power Supply Voltage 5.5 Enable Voltage	
LO^+ to LO^- Differential Voltage±2	
(+10dBm Equivalen	t)
RF ⁺ to RF ⁻ Differential Voltage±2	V
(+10dBm Equivalen	t)
Operating Ambient Temperature40°C to 85°	С
Storage Temperature Range –65°C to 125°	С
Maximum Junction Temperature 125°	С

PACKAGE/ORDER INFORMATION



Consult LTC Marketing for parts specified with wider operating temperature ranges.

AC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$. $V_{CC} = 5V$, EN = high, $f_{RF1} = 899.9$ MHz, $f_{RF2} = 900.1$ MHz, $f_{L0} = 901$ MHz, $P_{L0} = -10$ dBm unless otherwise noted. (Notes 2, 3) (Test circuit shown in Figure 2)

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Frequency Range				0.8 to 1.5		GHz
LO Power				−13 to −2		dBm
Conversion Gain	Voltage Gain, Load Impedan	ce = 1k	2	4.3		dB
Conversion Gain Variation vs Temperature	-40°C to 85°C			0.01		dB/°C
Noise Figure		R1 = 8.2Ω R1 = 3.3Ω, P _{L0} = -5dBm		11.4 12.8		dB dB
Input 3rd Order Intercept	2-Tone, -10dBm/Tone, $\Delta f = 200 kHz$	R1 = 8.2Ω R1 = 3.3Ω, P _{L0} = -5dBm		17.0 21.5		dBm dBm
Input 2nd Order Intercept	Input = -10dBm	R1 = 8.2Ω R1 = 3.3Ω, P _{L0} = -5dBm		46.0 52.0		dBm dBm
Input 1dB Compression	R1 = 8.2Ω			6.6		dBm
Baseband Bandwidth				260		MHz
I/Q Gain Mismatch	(Note 4)			0.2	0.7	dB
I/Q Phase Mismatch	(Note 4)			1		degree
Output Impedance	Differential			120		Ω
LO to RF Leakage				-65		dBm
RF to LO Isolation				57		dB

DC ELECTRICAL CHARACTERISTICS $T_A = 25^{\circ}C$. $V_{CC} = 5V$ unless otherwise noted.

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Supply Voltage		4		5.25	V
Supply Current		80	117	150	mA
Shutdown Current	EN = Low			20	μA
Turn-On Time			120		ns
Turn-Off Time			650		ns
EN = High (On)		1.6			V
EN = Low (Off)				1.3	V
EN Input Current	V _{ENABLE} = 5V		2		μA
$\label{eq:output} \hline \hline Output DC Offset Voltage \\ (I_{OUT}^+ - I_{OUT}^- , Q_{OUT}^+ - Q_{OUT}^-) \\ \hline \hline \hline \\$	$f_{LO} = 901$ MHz, $P_{LO} = -10$ dBm		1	25	mV
Output DC Offset Variation vs Temperature	-40°C to 85°C		20		µV/°C

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime.

Note 3: Specifications over the -40° C to 85° C temperature range are assured by design, characterization and correlation with statistical process control.

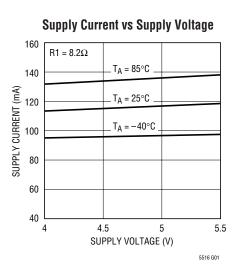
Note 4: Measured at $P_{RF} = -10$ dBm and output frequency = 1MHz.

Note 2: Tests are performed as shown in the configuration of Figure 2 with $R1 = 8.2\Omega$, unless otherwise noted.

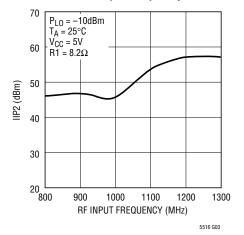


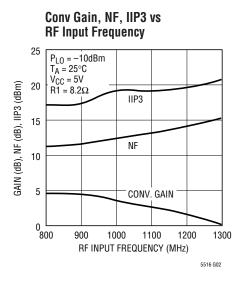
TYPICAL PERFORMANCE CHARACTERISTICS

(Test circuit optimized for 900MHz operation as shown in Figure 2)

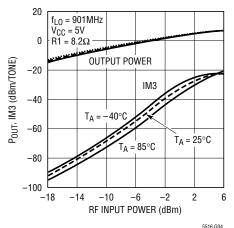


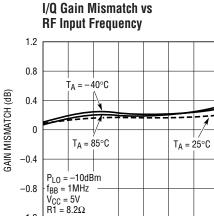
IIP2 vs RF Input Frequency

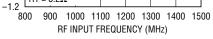




I/Q Output Power, IM3 vs RF Input Power







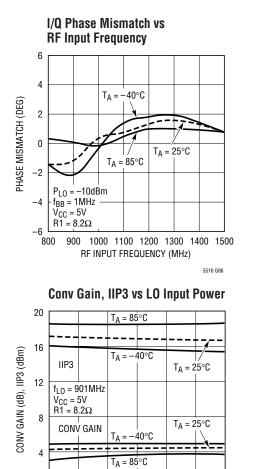


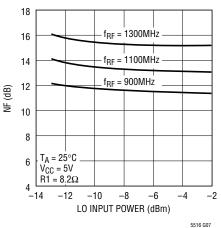
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5516 G05

TYPICAL PERFORMANCE CHARACTERISTICS

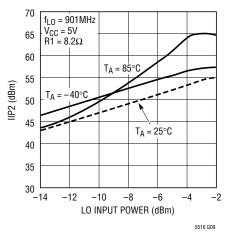
(Test circuit optimized for 900MHz operation as shown in Figure 2)

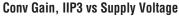


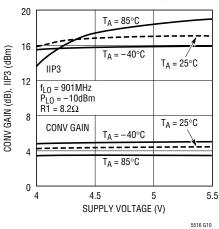


NF vs LO Input Power

IIP2 vs LO Input Power









0 ∟ -14

-12

-10

-8

LO INPUT POWER (dBm)

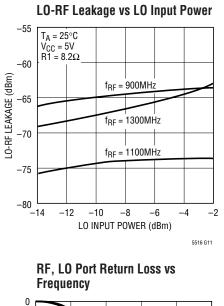
-6

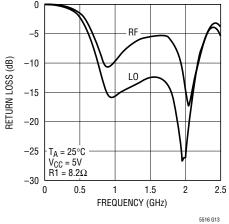
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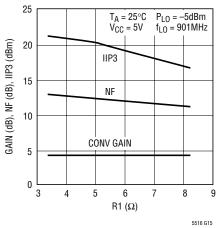
5516 G08

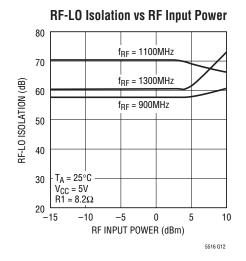
TYPICAL PERFORMANCE CHARACTERISTICS (Test circuit optimized for 900MHz operation as shown in Figure 2)



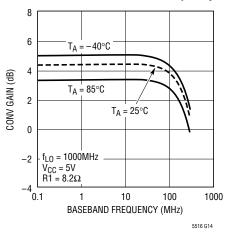


Conv Gain, NF, IIP3 vs R1

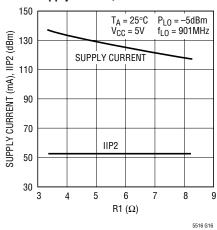




Conv Gain vs Baseband Frequency



Supply Current, IIP2 vs R1



PIN FUNCTIONS

GND (Pins 1, 4): Ground Pin.

RF⁺, RF⁻ (Pins 2, 3): Differential RF Input Pins. These pins are internally biased to 1.54V. They must be driven with a differential signal. An external matching network is required for impedance transformation.

V_{CC} (Pins 5, 8, 9, 12): Power Supply Pins. These pins should be decoupled using 1000pF and 0.1µF capacitors.

 V_{CM} (Pin 6): Common Mode and DC Return for the I-Mixer and Q-Mixer. An external resistor must be connected between this pin and ground to set the dc bias current of the I/Q demodulator.

EN (Pin 7): Enable Pin. When the input voltage is higher than 1.6V, the circuit is completely turned on. When the input voltage is less than 1.3V, the circuit is turned off.

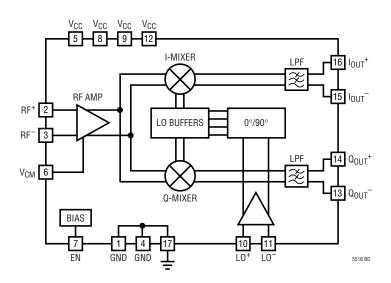
LO+, **LO-** (**Pins 10, 11**): Differential Local Oscillator Input Pins. These pins are internally biased to 2.44V. They can be driven single-ended by connecting one to an AC ground through a 1000pF capacitor. However, differential input drive is recommended to minimize LO feedthrough to the RF input pins.

 Q_{OUT}^{-} , Q_{OUT}^{+} (Pins 13, 14): Differential Baseband Output Pins of the Q-Channel. The internal DC bias voltage is V_{CC} -0.68V for each pin.

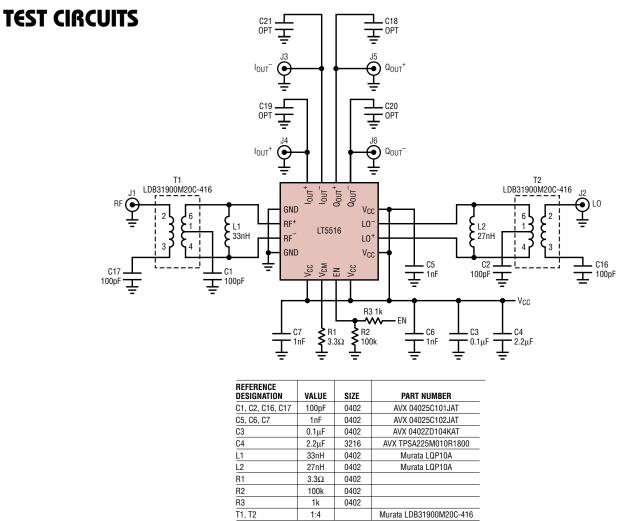
 I_{OUT} , I_{OUT} (Pins 15, 16): Differential Baseband Output Pins of the I-Channel. The internal DC bias voltage is V_{CC} -0.68V for each pin.

GROUND (Pin 17, Backside Contact): Ground Return for the Entire IC. This pin must be soldered to the printed circuit board ground plane.

BLOCK DIAGRAM







7	2.2μι	0210	AVA II OALLOWOTOTTTOOO
1	33nH	0402	Murata LQP10A
2	27nH	0402	Murata LQP10A
1	3.3Ω	0402	
2	100k	0402	
3	1k	0402	
1, T2	1:4		Murata LDB31900M20C-416
			5516 F02

Figure 2. 900MHz Evaluation Circuit Schematic

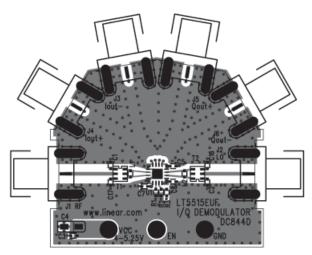


Figure 3. Topside of Evaluation Board

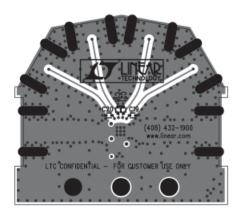


Figure 4. Bottom Side of Evaluation Board





APPLICATIONS INFORMATION

The LT5516 is a direct I/Q demodulator targeting high linearity receiver applications, including wireless infrastructure. It consists of an RF amplifier, I/Q mixers, a quadrature LO carrier generator and bias circuitry.

The RF signal is applied to the inputs of the RF amplifier and is then demodulated into I/Q baseband signals using quadrature LO signals. The quadrature LO signals are internally generated by precision 90° phase shifters. The demodulated I/Q signals are lowpass filtered internally with a -3dB bandwidth of 265MHz. The differential outputs of the I-channel and Q-channel are well matched in amplitude; their phases are 90° apart.

RF Input Port

Differential drive is highly recommended for the RF inputs to minimize the LO feedthrough to the RF port and to maximize gain. (See Figure 2.) A 1:4 transformer is used on the demonstration board for wider bandwidth matching. To assure good NF and maximize the demodulator gain, a low loss transformer is employed. Shunt inductor L1, with high resonance frequency, is required for proper impedance matching. Single-ended to differential conversion can also be implemented using narrow band, discrete L-C circuits to produce the required balanced waveforms at the RF⁺ and RF⁻ inputs.The differential impedance of the RF inputs is listed in Table 1.

FREQUENCY	DIFFERENTIAL INPUT	INPUT DIFFERENTIA		
(MHz)	IMPEDANCE (Ω)	MAG	ANGLE (°)	
800	169.7-j195.2	0.779	-16.9	
900	156.1-j181.8	0.766	-18.3	
1000	145.6-j170.0	0.753	-19.6	
1100	137.3-j160.0	0.740	-20.9	
1200	130.7-j152.1	0.729	-21.9	
1300	124.9-j144.7	0.718	-23.0	
1400	119.9-j138.3	0.707	-24.0	
1500	115.7-j133.1	0.698	-24.9	

Table 1. RF Input Differential Impedance

The RF⁺ and RF⁻ inputs (Pins 2, 3) are internally biased at 2.44V. These two pins should be DC blocked when connected to ground or other matching components. The RF input equivalent circuit is shown in Figure 5.

An external resistor (R1) is connected to Pin 6 (V_{CM}) to set the optimum DC current for I/Q mixer linearity. The IIP3 can be improved with a smaller R1 at a price of slightly higher NF and I_{CC}. The RF performances of NF, IIP3 and IIP2 vs R1 are shown in the Typical Performance Characteristics.

LO Input Port

The LO inputs (Pins 10,11) should be driven differentially to minimize LO feedthrough to the RF port. This can be accomplished by means of a single-ended to differential conversion as shown in Figure 2. L4, the 27nH shunt inductor, serves to tune out the capacitive component of the LO differential input. The resonance frequency of the inductor should be greater than the operating frequency. A 1:4 transformer is used on the demo board to match the 200 Ω on-chip resistance to a 50 Ω source. Figure 6 shows the LO input equivalent circuit and the associated matching network.

Single-ended to differential conversion at the LO inputs can also be implemented using a discrete L-C circuit to produce a balanced waveform without a transformer.

An alternative solution is a simple single-ended termination. However, the LO feedthrough to RF may be degraded. Either LO⁺ or LO⁻ input can be terminated to a 50Ω source with a matching circuit, while the other input is connected to ground through a 100pF bypass capacitor.

Table 2 shows the differential input impedance of the LO input port.

Table 2.	L0	Input	Differential	Impedance
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FREQUENCY DIFFERENTIAL INPUT		DIFFERENTIAL S11		
(MHz)	IMPEDANCE (Ω)	MAG	ANGLE (°)	
800	118.4-j65.1	0.552	-22.5	
900	110.1-j66.7	0.517	-25.4	
1000	102.2-j67.5	0.512	-28.5	
1100	94.6-j67.2	0.505	-31.8	
1200	87.5-j66.1	0.498	-35.0	
1300	80.8-j64.4	0.490	-38.3	
1400	74.7-j62.1	0.480	-42.0	
1500	69.3-j59.4	0.469	-45.8	



APPLICATIONS INFORMATION

I-Channel and Q-Channel Outputs

Each of the I-channel and Q-channel outputs is internally connected to V_{CC} though a 60Ω resistor. The output dc bias voltage is V_{CC} -0.68V. The outputs can be DC coupled or AC coupled to the external loads. The differential output impedance of the demodulator is 120Ω in parallel with a 5pF internal capacitor, forming a lowpass filter with a -3dB corner frequency at 265MHz. R_{LOAD} (the single-ended load resistance) should be larger than 600Ω to assure full gain. The gain is reduced by $20 \cdot \log(1 + 120\Omega/R_{LOAD})$ in dB when the differential output is terminated by R_{LOAD} . For instance, the gain is reduced by 6.85dB when each output pin is connected to a 50Ω load (100Ω differential load). The output should be taken differentially (or by using differential-to-single-ended conversion) for best RF performance, including NF and IM2.

The phase relationship between the I-channel output signal and Q-channel output signal is fixed. When the LO input frequency is larger (or smaller) than the RF input frequency, the Q-channel outputs (Q_{OUT}^+, Q_{OUT}^-) lead (or lag) I-channel outputs (I_{OUT}^+, I_{OUT}^-) by 90°.

When AC output coupling is used, the resulting highpass filter's -3dB roll-off frequency is defined by the R-C constant of the blocking capacitor and R_{LOAD}, assuming R_{LOAD} > 600 Ω .

Care should be taken when the demodulator's outputs are DC coupled to the external load, to make sure that the I/Q mixers are biased properly. If the current drain from the outputs exceeds 6mA, there can be significant degradation of the linearity performance. Each output can sink no more than 13mA when the outputs are connected to an external load with a DC voltage higher than $V_{CC} - 0.68V$. The I/Q output equivalent circuit is shown in Figure 7.

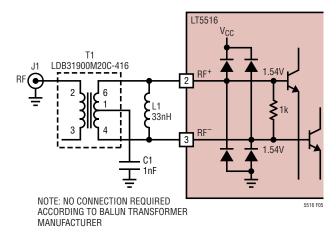
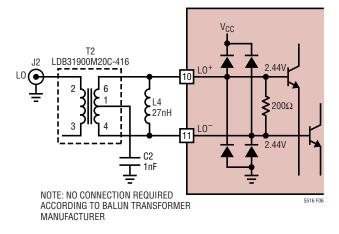


Figure 5. RF Input Equivalent Circuit with External Matching



APPLICATIONS INFORMATION



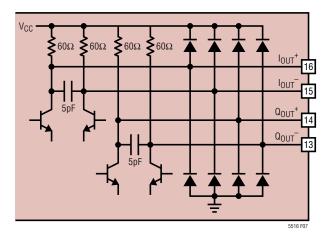
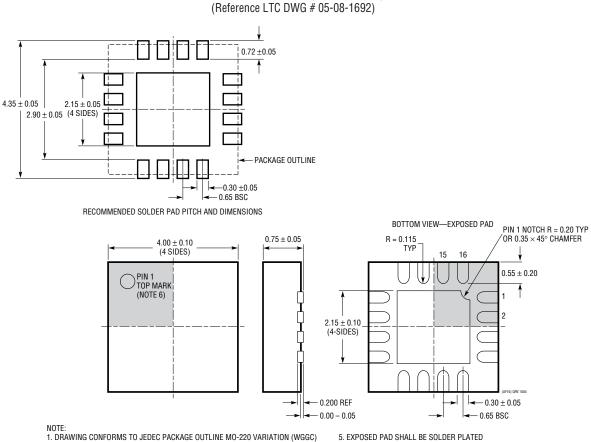


Figure 7. I/Q Output Equivalent Circuit

6. SHADED AREA IS ONLY A REFERENCE FOR PIN 1 LOCATION ON THE TOP AND BOTTOM OF PACKAGE



PACKAGE DESCRIPTION



UF Package 16-Lead Plastic QFN (4mm \times 4mm)

1. DRAWING CONFORMS TO JEDEC PACKAGE OUTLINE MO-220 VARIATION (WGGC) 2. DRAWING NOT TO SCALE 3. ALL DIMENSIONS ARE IN MILLIMETERS

A. DIMENSIONS OF EXPOSED PAD ON BOTTOM OF PACKAGE DO NOT INCLUDE MOLD FLASH. MOLD FLASH, IF PRESENT, SHALL NOT EXCEED 0.15mm ON ANY SIDE



Information furnished by Linear Technology Corporation is believed to be accurate and reliable. However, no responsibility is assumed for its use. Linear Technology Corporation makes no representation that the interconnection of its circuits as described herein will not infringe on existing patent rights.

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS		
RF Power Controllers				
LTC1757A	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones		
LTC1758	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones		
LTC1957	RF Power Controller	Multiband GSM/DCS/GPRS Mobile Phones		
LTC4400	SOT-23 RF PA Controller	Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 450kHz Loop BW		
LTC4401	SOT-23 RF PA Controller	Multiband GSM/DCS/GPRS Phones, 45dB Dynamic Range, 250kHz Loop BW		
LTC4403	RF Power Controller for EDGE/TDMA	Multiband GSM/GPRS/EDGE Mobile Phones		
LT5500	RF Front End	Dual LNA gain Setting +13.5dB/–14dB at 2.5GHz, Double-Balanced Mixer, $1.8V \leq V_{SUPPLY} \leq 5.25V$		
LT5502	400MHz Quadrature Demodulator with RSSI	1.8V to 5.25V Supply, 70MHz to 400MHz IF, 84dB Limiting Gain, 90dB RSSI Range		
LT5503	1.2GHz to 2.7GHz Direct IQ Modulator and Up Converting Mixer	1.8V to 5.25V Supply, Four-Step RF Power Control, 120MHz Modulation Bandwidth		
LT5504	800MHz to 2.7GHz RF Measuring Receiver	80dB Dynamic Range, Temperature Compensated, 2.7V to 5.5V Supply		
LTC5505	300MHz to 3.5GHz RF Power Detector	>40dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply		
LT5506	500MHz Quadrature IF Demodulator with VGA	1.8V to 5.25V Supply, 40MHz to 500MHz IF, –4dB to 57dB Linear Power Gain		
LTC5507	100kHz to 1GHz RF Power Detector	48dB Dynamic Range, Temperature Compensated, 2.7V to 6V Supply		
LTC5508	300MHz to 7GHz RF Power Detector	SC70 Package		
LTC5509	300MHz to 3GHz RF Power Detector	36dB Dynamic Range, SC70 Package		
LT5511	High Signal Level Up Converting Mixer	RF Output to 3GHz, 17dBm IIP3, Integrated LO Buffer		
LT5512	High Signal Level Down Converting Mixer	DC-3GHz, 20dBm IIP3, Integrated LO Buffer		

